10MQ060NPbF

# Schottky Rectifier, 2.1 A



- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level

### DESCRIPTION

The 10MQ060NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I <sub>F(AV)</sub>	DC	2.1	A	
V <sub>RRM</sub>		60	V	
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	40	A	
V <sub>F</sub>	1.5 Apk, T <sub>J</sub> = 125 °C	0.63	V	
TJ	Range	- 55 to 150	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	10MQ060NPbF	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	60	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	80	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I <sub>F(AV)</sub>	50 % duty cycle at $T_L$ = 120 °C, rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)		1.5	A
Maximum peak one cycle		5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	40	•
non-repetitive surge current See fig. 6	IFSM	10 ms sine or 6 ms rect. pulse		10	A
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 4 mH		2.0	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.0	А

\* Pb containing terminations are not RoHS compliant, exemptions may apply

Cathode

SMA

**PRODUCT SUMMARY** 

 $I_{F(AV)}$ 

 $V_{R}$ 

Anode

2.1 A

60 V





COMPLIANT

## 10MQ060NPbF

# Vishay High Power Products Schottky Rectifier, 2.1 A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	1 A	T <sub>.1</sub> = 25 °C	0.63	v
		1.5 A	1j=25 C	0.71	
		1 A	T 105 %0	0.57	
		1.5 A	T <sub>J</sub> = 125 °C	0.63	
Maximum reverse leakage current See fig. 2	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V Deted V	0.5	mA
		T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	7.5	
Threshold voltage	V <sub>F(TO)</sub>	T <sub>J</sub> = T <sub>J</sub> maximum		0.45	V
Forward slope resistance	r <sub>t</sub>			86.8	mΩ
Typical junction capacitance	CT	$V_R = 10 V_{DC}$ , $T_J = 25 \text{ °C}$ , test signal = 1 MHz		31	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

#### Note

<sup>(1)</sup> Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		- 55 to 150	°C	
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	80	°C/W	
Approximate weight			0.07	g	
Approximate weight			0.002	0Z.	
Marking device		Case style SMA (similar D-64)	V1H		

#### Note

<sup>(1)</sup>  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink



DC

2.0

1.6

2.4

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D = 0.20 D = 0.25

D = 0.33 ~ D = 0.50 <

D = 0.75

See note (1)

0.4

Square wave (D = 0.50) 80 % rated  $V_{B}$  applied

0.8

1.2

150

140

130

120

110

100

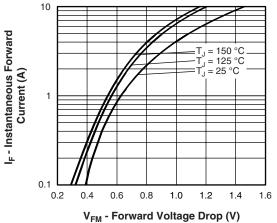
90

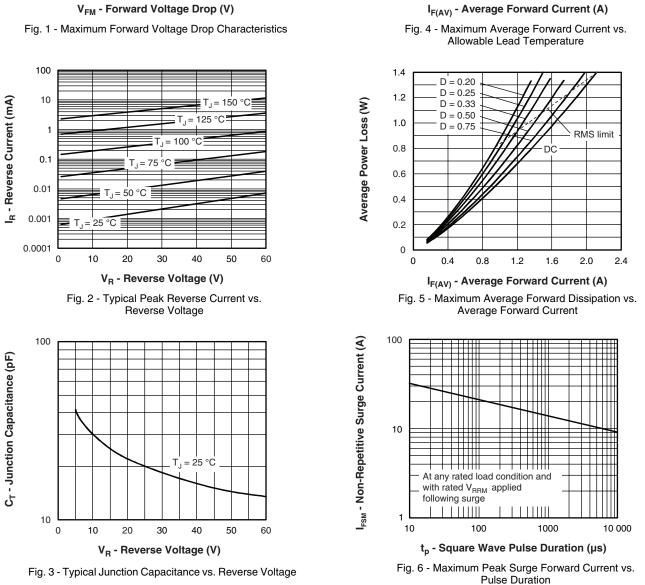
80

70

0

Allowable Case Temperature (°C)





#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

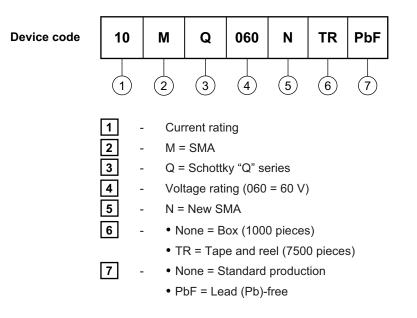
Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$ 

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Vishay High Power Products Schottky Rectifier, 2.1 A



### **ORDERING INFORMATION TABLE**



LINKS TO RELATED DOCUMENTS			
Dimensions	http://www.vishay.com/doc?95018		
Part marking information	http://www.vishay.com/doc?95029		
Packaging information	http://www.vishay.com/doc?95034		



Vishay

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